

PBRN113ZT

40 V, 600 mA NPN PB RET; R1 = 1 k Ω , R2 = 10 k Ω

31 March 2021

Product data sheet

1. General description

NPN low V_{CEsat} Performance-Based (PB) Resistor-Equipped Transistor (RET) in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package.

PNP complement: PBRP113ZT

2. Features and benefits

- · 600 mA output current capability
- Low collector-emitter saturation voltage V_{CEsat}
- High current gain h_{FF}
- Reduces component count
- Built-in bias resistors
- Reduces pick and place costs
- Simplifies circuit design
- ± 10 % resistor ratio tolerance

3. Applications

- · Digital application in automotive and industrial segments
- Switching loads
- · Medium current peripheral driver

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{CEO}	collector-emitter voltage	open base		-	-	40	V
Io	output current		[1]	-	-	600	mA
R1	bias resistor 1		[2]	0.7	1	1.3	kΩ
R2/R1	bias resistor ratio		[2]	9	10	11	

- [1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided, 35 µm copper, tin-plated and standard footprint.
- [2] See section "Test information" for resistor calculation and test conditions



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5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	I	input (base)]3	
2	GND	ground (emitter)		R1
3	O	output (collector)	SOT23	GND

6. Ordering information

Table 3. Ordering information

Type number	Package	ackage				
	Name	Description	Version			
PBRN113ZT	SOT23	plastic, surface-mounted package; 3 terminals; 1.9 mm pitch; 2.9 mm x 1.3 mm x 1 mm body	SOT23			

7. Marking

Table 4. Marking codes

Type number	Marking code[1]
PBRN113ZT	%7L

[1] % = placeholder for manufacturing site code

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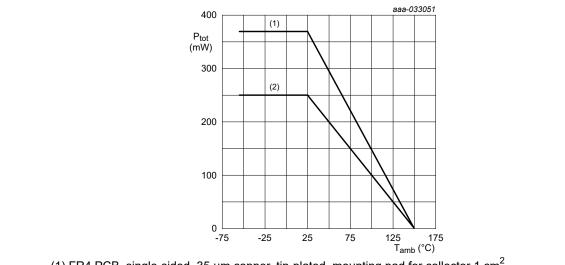
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{CBO}	collector-base voltage	open emitter		-	40	V
V_{CEO}	collector-emitter voltage	open base		-	40	V
V_{EBO}	emitter-base voltage	open collector		-	5	V
VI	input voltage	positive		-	10	V
		negative		-	-5	V
Io	output current		[1]	-	600	mA
			[2]	-	700	mA
I _{ORM}	repetitive peak output current	$t_p \le 1 \text{ ms}; \ \delta \le 0.33$		-	800	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	250	mW
			[2]	-	370	mW
T _j	junction temperature			-	150	°C
T _{amb}	ambient temperature			-65	150	°C
T _{stg}	storage temperature			-65	150	°C

- Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided, 35 µm copper, tin-plated and standard footprint.
- Device mounted on an FR4 PCB, single-sided, 35 μm copper, tin-plated, mounting pad for collector 1 cm².



- (1) FR4 PCB, single-sided, 35 µm copper, tin-plated, mounting pad for collector 1 cm²
- (2) FR4 PCB, single-sided, 35 µm copper, tin-plated and standard footprint

Power derating curve Fig. 1.

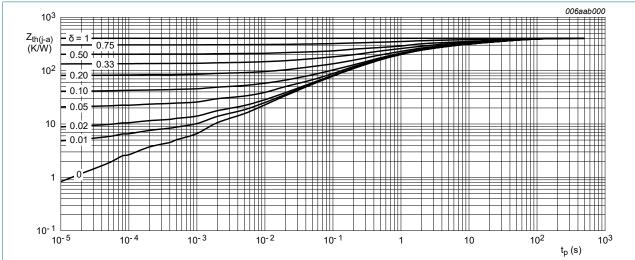
40 V, 600 mA NPN PB RET; R1 = 1 k Ω , R2 = 10 k Ω

9. Thermal characteristics

Table 6. Thermal characteristics

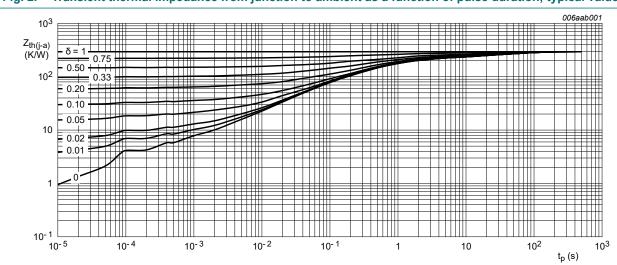
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from	in free air	[1]	-	-	500	K/W
	junction to ambient		[2]	-	-	338	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point			-	-	105	K/W

- [1] Device mounted on an FR4 PCB, single-sided, 35 µm copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided, 35 µm copper, tin-plated, mounting pad for collector 1 cm².



FR4 PCB, single-sided, 35 µm copper, tin-plated and standard footprint.

Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB, single-sided, 35 μm copper, tin-plated, mounting pad for collector 1 cm².

Fig. 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

40 V, 600 mA NPN PB RET; R1 = 1 k Ω , R2 = 10 k Ω

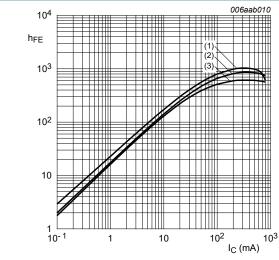
10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$V_{(BR)CBO}$	collector-base breakdown voltage	$I_C = 100 \ \mu A; I_E = 0 \ A; T_{amb} = 25 \ ^{\circ}C$		40	-	-	V
V _{(BR)CEO}	collector-emitter breakdown voltage	$I_C = 10 \text{ mA}; I_B = 0 \text{ A}; T_{amb} = 25 \text{ °C}$		40	-	-	V
I _{CBO}	collector-base cut-off current	V _{CB} = 30 V; I _E = 0 A; T _{amb} = 25 °C		-	-	100	nA
I _{CEO}	collector-emitter cut-off current	$V_{CE} = 30 \text{ V}; I_{B} = 0 \text{ A}; T_{amb} = 25 \text{ °C}$		-	-	0.5	μΑ
I _{EBO}	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; I_{C} = 0 \text{ A}; T_{amb} = 25 \text{ °C}$		-	-	0.8	mA
h _{FE}	DC current gain	V _{CE} = 5 V; I _C = 50 mA; T _{amb} = 25 °C		300	450	-	
		V_{CE} = 5 V; I_{C} = 300 mA; pulsed; t_{p} ≤ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C		500	750	-	
		V_{CE} = 5 V; I_{C} = 600 mA; pulsed; t_{p} ≤ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C		500	720	-	
		V_{CE} = 5 V; I_{C} = 800 mA; pulsed; $t_{p} \le$ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C		450	650	-	
V _{CEsat}	collector-emitter	I_C = 50 mA; I_B = 2.5 mA; T_{amb} = 25 °C		-	25	35	mV
	saturation voltage	I_C = 200 mA; I_B = 10 mA; pulsed; $t_p \le$ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C		-	60	85	mV
		I_C = 500 mA; I_B = 10 mA; pulsed; $t_p \le$ 300 μs; $δ \le 0.02$; T_{amb} = 25 °C		-	160	220	mV
		I_C = 600 mA; I_B = 6 mA; pulsed; $t_p \le$ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C		-	270	550	mV
		I_C = 800 mA; I_B = 8 mA; pulsed; $t_p \le$ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C		-	560	1150	mV
V _{I(off)}	off-state input voltage	V _{CE} = 5 V; I _C = 100 μA; T _{amb} = 25 °C		0.3	0.5	1	V
V _{I(on)}	on-state input voltage	V _{CE} = 0.3 V; I _C = 20 mA; T _{amb} = 25 °C		0.4	0.7	1.4	V
R1	bias resistor 1		[1]	0.7	1	1.3	kΩ
R2/R1	bias resistor ratio		[1]	9	10	11	
C _c	collector capacitance	V_{CB} = 10 V; I_{E} = 0 A; i_{e} = 0 A; f = 1 MHz; T_{amb} = 25 °C		-	7	-	pF

^[1] See section "Test information" for resistor calculation and test conditions

40 V, 600 mA NPN PB RET; R1 = 1 k Ω , R2 = 10 k Ω

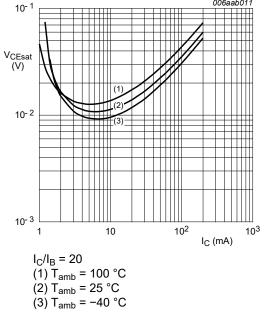


$$(1) T_{amb} = 100 ^{\circ}$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

V_{CE} = 5 V (1) T_{amb} = 100 °C (2) T_{amb} = 25 °C (3) T_{amb} = -40 °C

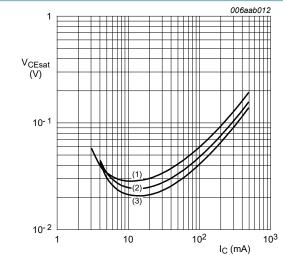
Fig. 4. DC current gain as a function of collector current; typical values



$$(1) T_{amb} = 100 °C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

Fig. 5. Collector-emitter saturation voltage as a function of collector current; typical values



 $I_{\rm C}/I_{\rm B}=50$

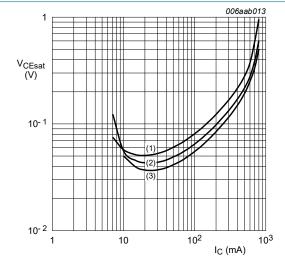
(1)
$$T_{amb} = 100 \,^{\circ}C$$

(2) $T_{amb} = 25 \,^{\circ}C$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3) $T_{amb} = -40 \, ^{\circ}C$

Fig. 6. Collector-emitter saturation voltage as a function of collector current; typical values



 $I_{\rm C}/I_{\rm B} = 100$

$$(1) T_{amb} = 100 °C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3) $T_{amb} = -40 \, ^{\circ}C$

Fig. 7. Collector-emitter saturation voltage as a function of collector current; typical values

40 V, 600 mA NPN PB RET; R1 = 1 k Ω , R2 = 10 k Ω

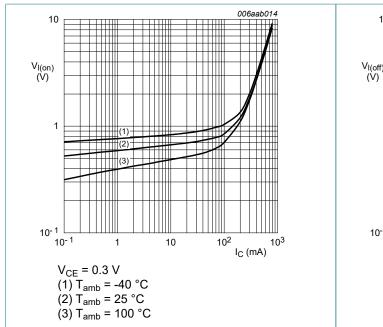
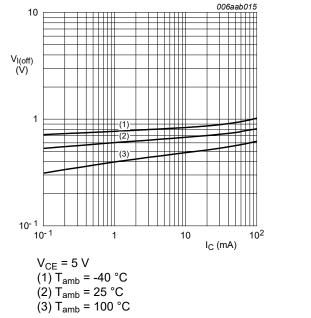


Fig. 8. On-state input voltage as a function of collector current; typical values



Off-state input voltage as a function of collector current; typical values

40 V, 600 mA NPN PB RET; R1 = 1 k Ω , R2 = 10 k Ω

11. Test information

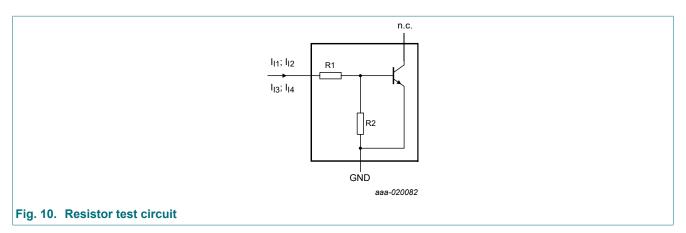
Resistor calculation

• Calculation of bias resistor 1 (R1)

$$R_{I} = \frac{V(I_{I2}) - V(I_{I1})}{I_{I2} - I_{I1}}$$

· Calculation of bias resistor ratio (R2/R1)

$$\frac{R2}{R1} = \frac{V(I_{I3})}{R1 \cdot I_{I3}} - 1$$

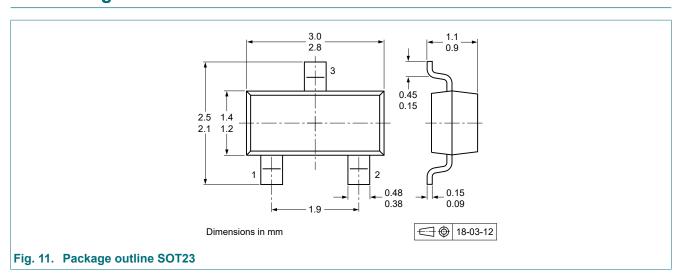


Resistor test conditions

Table 8. Resistor test conditions

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Type number	R1 (kΩ)	R2 (kΩ)	Test conditions	Test conditions					
			I ₁₁	I ₁₂	I ₁₃				
PBRN113ZT	1	10	700 µA	800 μΑ	-750 μA				

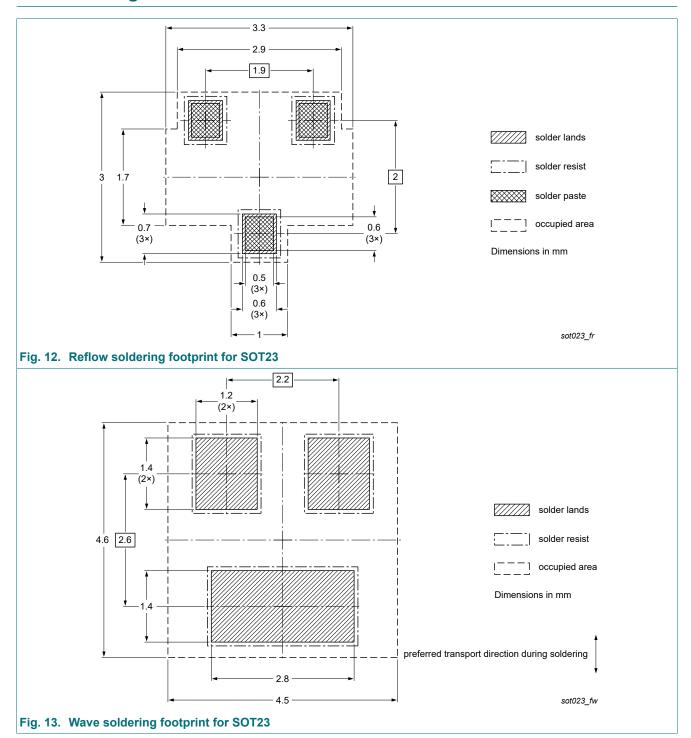
12. Package outline



PBRN113ZT

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13. Soldering



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14. Revision history

Table 9. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes			
PBRN113ZT v.2	20210331	Product data sheet	-	PBRN113Z_SER_1			
Modifications:		Types in SOT346 and SOT54 are obsolete Product description changed from BISS to PB RET					
PBRN113Z_SER_1	20070226	Product data sheet	-	-			

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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